

One-Time Programmable 4-Bit Single-Chip Microcontroller

The LC65P29 is a one-time programmable (on-chip PROM) version of Sanyo's LC6529N/F/L 4-bit single-chip CMOS microcontroller. It provides identical functionality to, and pin compatibility with, the mask ROM versions of the LC6529N/F/L, and provides a 1-KB internal PROM. The LC65P29 is provided in DIP24S and MFP30S plastic packages and the program can be written by the customer, thus makes this IC appropriate for the limited-run products and the startup of initial production of new products. Furthermore, it can provide reduced changeover periods when end product specifications change.

Additionally, the LC65P29 can function as a one-time programmable PROM version of the Sanyo LC6527N/F/L and LC6528N/F/L by using the 29T27 adapter socket.

Features

• Mask option settings can be switched by setting PROM data.

All options, except for the port output circuit type can be set with PROM data.

- 1-KB PROM
- PROM data security function
- Pin compatible with the mask ROM version
- Instruction cycle time: 0.92 µs to 20 µs
- Packages: DIP24S and MFP30S

Package Dimensions

unit: mm

3067-DIP24S(300mil)



unit: mm

3216-MFP30S(375mil)



Note: The package dimension figures are provide for reference purposes without dimensional tolerances. Contact your Sanyo representative for the official package dimension figures.

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LC65P29

Notes on Sanyo ROM Writing Services

Sanyo provides a for-fee ROM writing service that consists of writing the one-time programmable ROM, printing, screening, and readout verification. Contact your Sanyo representative for details.

Pin Assignments



Product Series Structure

Type number.	Number of pins	ROM capacity	RAM capacity	Package
LC6527N/F/L, LC6528N/F/L	18	1K, 0.5K	64W, 32W	DIP18, MFP18
LC6529N/F/L	24/30	1K	64W	DIP24S, SSOP24, MFP30S
LC65E29	24/30	1K	64W	DIC24S, MFC30S
LC65P29	24/30	1K	64W	DIP24S, MFP30S
LC6543N/F/L, LC6546N/F/L	30	2K, 1K	128W, 64W	DIP30S, MFP30S
LC65E43	30	2K	128W, 64W	DIC30S, MFC30S
LC65P43	30	2K	128W, 64W	DIP30S, MFP30S
LC651104N/F/L, LC651102N/F/L	30	4K, 2K	256W	DIP30S, MFP30S
LC651204N/F/L, LC651202N/F/L	30	4K, 2K	256W	DIP30S, MFP30S
LC65E1104	30	4K	256W	DIC30S, MFC30S
LC65P1104	30	4K	256W	DIP30S, MFP30S

Usage Notes

The LC65P29 is designed for program development and evaluation for systems that use the LC6529N/F/L. The following points require attention when using this product.

• Mounting notes

Due to the nature of the device, one-time programmable microcontrollers cannot be fully tested prior to shipment. This means that users must perform the screening process described on page 14.

• ROM ordering procedure when using the Sanyo for-fee ROM writing service

The customer must abide by the following when using the Sanyo for-fee ROM writing service:

- When ordering both one-time programmable and mask versions at the same time

The customer must provide an EPROM for the mask version, the mask version order forms, and the one-time programmable version order forms.

- When order only the one-time programmable version
 - The customer must provide an EPROM for the one-time programmable version and the one-time programmable version order forms. The end area in the EPROM (locations 400 to 404H) is the option specification area and the customer must program the option specification data in that area. The customer must use the cross assembler specified by Sanyo.

٠	Differences	between	the L	C65P29	and the	e LC6529N/F/L
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	Parameter	LC65P29	LC6529N	LC6529F	LC6529L		
	Ports C and D output option during reset	High or low can be specified (option code)	High or low can be specified (mask option)				
	Port output type during reset	Open-drain output only (ports A, C, and D)	Open-drain or pull-up register can be specified (mask option)				
	Oscillator circuit option	CF/RC or EXT can be specified (option code)	CF/RC or EXT can be specified (mask option)	CF or EXT can be specified (mask option)	CF/RC or EXT can be specified (mask option)		
Option	Divider circuit option	1/1, 1/3, or 1/4 can be specified (option code)	1/1,1/3 or 1/4 can be specified (mask option)	Only 1/1 is possible (mask option)	1/1,1/3 or 1/4 can be specified (mask option)		
	Comparator input and port E input option	Comparator or port E can be specified (option code)	Comparator or port E can be specified (mask option)				
	Comparator function option	Feedback resistor present or absent can be specified (option code)	Feedback resistor present or absent can be specified (mask option)				
	Minimum cycle time	0.92 $\mu s~(V_{DD} \geq 3.0~V)$	2.77 $\mu s~(V_{DD} \geq 3.0~V)$	0.92 µs (V _{DD} ≥ 3.0 V)	3.84 $\mu s~(V_{DD} \geq 2.2~V)$		
stic	Operating temperature	−30 to +70°C		–40 to +85°C			
Characteristic	Supply voltage	3.0 to 6.0 V	3.0 to 6.0 V	3.0 to 6.0 V	2.2 to 6.0 V		
Char	Current drain	5.0 mA typ.	2.0 mA typ.	2.5 mA typ.	2.0 mA typ.		
	Reset port input low-level current	–50 μA typ.		–10 μA typ.			
Other items	Package	DIP24S, MFP30S	DIP24S, SSOP24, MFP30S				

System Block Diagram



RAM: Data memory

- ALU: Arithmetic and logic unit
- DP: Data pointer
- E: E register
- AC: Accumulator
- OSC: Oscillator circuit
- TM: Timer
- STS: Status register

EPROM: Program memory

- PC: Program counter
- I.R: Instruction register
- I.DEC: Instruction decoder
- CF: Carry flag
- ZF: Zero flag
- TMF: Timer overflow flag

Pin Descriptions

Pin name	Number of pins	I/O	Function	Option	State during reset	Function in PROM mode
V _{DD} V _{SS}	1 1	_	Power supply. Must be connected to +5 V during normal operation. Power supply. Must be connected to 0 V during normal operation.		_	
OSC1/CE OSC2/TA	1	I O	System clock oscillator connections. Leave OSC2 open and input the external clock to OSC1 if an external clock is used.	1.Two-pin RC oscillator (Single-pin external clock input) 2.Two-pin ceramic oscillator 3.Divisor option: 1/1, 1/3, or 1/4		EPROM contorol signal inputs CE TA
PA0/A6 PA1/A7 PA2/A8 PA3/A9	4	I/O	 I/O ports A0 to A3 Input in 4-bit units (IP instruction) Output in 4-bit units (OP instruction) Data testing in 1-bit units (BP and BNP instructions) Data set and clear operations in 1-bit units (SPB and RPB instructions) PA3 is used for standby mode control. Applications must assure that chattering (key bounce) noise is not input during a HALT instruction execution cycle. 	Open-drain output	High-level output (The n-channel output transistor turned off.)	• Address inputs A6 to A9
PC0/D0 PC1/D1 PC2/D2 PC3/D3	4	I/O	 I/O ports C0 to C3 The pin functions are identical to those of pins A0 to A3. However, there is no standby mode control function. The output during a reset can be specified to be either high or low as an option. 	 Open-drain output High-level output during reset Low-level output during reset Selection of items 2 or 3 is in 4-bit units. 	 High-level output Low-level output (Depending on an option selection.) 	• Data I/O D0 to D3
PD0/D4 PD1/D5 PD2/D6 PD3/D7	4	I/O	 I/O ports D0 to D3 The pin functions are identical to those of pins PC0 to PC3. 	The same as for pins PC0 to PC3	The same as pins PC0 to PC3	• Data I/O D4 to D7
PE0/CMP0/A0 PE1/CMP1/A1 PE2/CMP2/A2	4	I	 When comparator input is selected: CMP0 and CMP1 use V_{REF}0 as the reference voltage, CMP2 and CMP3 use V_{REF}1 as the reference voltage, Comparator inputs CMP0 to CMP3 Data input in 4-bit units (IP instruction) Data testing in 1-bit units (BP and BNP instructions) 	 Comparator input Port E input No feedback resistor Feedback resistor present Selection of items 1 or 2 is in 4-bit units. 		Address inputs A0 to A3
PE3/CMP3/A3	4	I	 When input is selected for port E Input ports E0 to E3 Input in 4-bit units (IP instruction) Data testing in 1-bit units (BP and BNP instructions) 	Items 3 and 4 are only specified when item 1 is selected.		
V _{REF} 0/A4 V _{REF} 1/A5/ DASEC	2	I	 Comparator reference voltage inputs V_{REF}0 and V_{REF}1 V_{REF}0 is the reference voltage input for CMP0 and CMP1. V_{REF}1 is the reference voltage input for CMP2 and CMP3. When PE0/CMP0 to PE3/CMP3 are selected to function as port E inputs, these pins are connected to V_{SS}. 			 Address inputs A4 and A5 EPROM control signal input DASEC
RES/V _{PP} /OE	1	I	 System reset input Connect an external capacitor to effect the power-on reset. Input a low level for at least 4 clock cycles to effect a reset restart. 			• EPROM control signal input V _{PP} / OE
TEST/EPMOD	1	1	 IC test pin This pin must be connected to V_{SS} during normal operation. 			• EPROM control signal input EPMOD

User Options

• Ports C and D output level during reset option

One of the following two options for the output level during a reset can be selected for each of the ports C and D in 4-bit units.

Option	Conditions and notes
High-level output at reset	Ports C and D in 4-bit units
Low-level output at reset	Ports C and D in 4-bit units

• Port output circuit type option

The I/O ports A, C, and D are always set up as open-drain outputs.



• Oscillator circuit options



• Divisor option

Option	Circuit	Conditions and notes
No divisor (1/1)	Timing generator	Can be used with any of the 3 oscillator options. (N, F, and L versions)
Divide-by-3 circuit (1/3)	Timing generator	Can only be used with the external clock and ceramic oscillator options. (N and L versions)
Divide-by-4 circuit (1/4)	□ fosc fosc 4 Timing generator	Can only be used with the external clock and ceramic oscillator options. (N and L versions)

Comparator input/port E input option

Whether the 4 port pins PE0/CMP0, PE1/CMP1, PE2/CMP2, and PE3/CMP3 function as comparator inputs or as port E inputs can be selected.

Option	Conditions and notes
Comparator inputs	All 4 bits specified together
Port E inputs	All 4 bits specified together

• Comparator function option

One of two options relating to the comparator function can be selected.

Option	Circuit	Conditions and notes
No feedback resistor	CMP0 to 3	The comparator can be used without hysteresis.
Feedback resistor present		When used with an added external resistor, the comparator can be used with hysteresis.

Usage Procedures

• Option specification procedures

User options can be selected interactively by running the LC6529 option entry software (SU60K). This creates an option file (file.opt).

Assembling the user program with the macro assembler (M60K) creates an object file. An evaluation file (file.eva) can be created by linking the object file and the option file with the linker (L60K). Then, a HEX format object file, which includes both the user program and the mask options, can be created by converting the evaluation file with the file conversion software (E2H60K). This creates the option codes in the option specification area (locations 400 to 404H). It is also possible to store data directly to the option specification area. Refer to the option code creation table on page 9 to do this.

Refer to the "LC65/66K Software Manual" for details.

• EPROM programming procedure

A general-purpose EPROM programmer can be used to write the created data to the LC65P29 by using a special-purpose write conversion board (either the W65EP29D or the W65EP29M).

— The EPROM programmers listed below can be used.

Manufacturer	Models that can be used
ADVANTEST	R4945, R4944A, R4943 or equivalent
ANDO	—
AVAL	—
MINATO Electronics	—

— The "27512 (VPP: 12.5 V) Intel fast write" method must be used for writing. Specify locations 0 to 404 as the address settings, and make sure that the DASEC jumper is in the off position.

• Using the data security function

The data security function is a function that prevents data written previously to the microcontroller EPROM from being read out. Use the following procedure to apply the data security to the LC65P29.

- 1. Set the DASEC jumper on the write conversion board to the on position.
- 2. Write the data once again.

At this point, the EPROM writer will indicate an error since this function has operated, but actually, no error has occurred in either the programmer or the IC.

Notes: • The data security function will not be applied if the data value FF is written to all address in step 2.

- The data security function will not be applied if the sequence $BLANK \rightarrow PROGRAM \rightarrow VERIFY$ is performed at step 2.
- Always return the jumper to the off position after performing this procedure.

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• For normal writing



• For writing with the security function applied



· Option data area and definition



Note: Although all ports are set up to be open-drain outputs regardless of the port option data in the LC65P29, be sure to specify the port option data if you are using the LC6529N/F/L (mask ROM version).

Parameter	Symbol	Applicable	Conditions		Unit		
Parameter	Symbol	pins/notes	Conditions	min	typ	max	Unit
Maximum supply voltage	V _{DD} max	V _{DD}		-0.3		+7.0	V
Output voltage	Vo	OSC2		Values up	to the genera are allowed	•	V
Input voltage	V _I 1	OSC1*1		-0.3		V _{DD} + 0.3	V
	V _I 2	TEST, RES		-0.3		V _{DD} + 0.3	V
	V _I 3	Ports with PE specifications		-0.3		V _{DD} + 0.3	V
I/O voltage	V _{IO}	PA, PC, PD		-0.3		+15	mA
Peak output current	I _{OP}	PA, PC, PD		-2		+20	mA
	I _{OA}	PA, PC, PD	The 100 ms average per pin	-2		+20	mA
Average output current	ΣI_{OA} 1	PA	The total current for pins PA0 to PA3*2	-6		+40	mA
	Σ I _{OA} 2	PC, PD	The total current for pins PC0 to PC3 and PD0 to PD3 *3	-14		+90	mA
Allowable newer discinction	Pdmax1		Ta = -30 to +70°C(DIP24S)			360	mW
Allowable power dissipation	Pdmax2		Ta = -30 to +70°C(MFP30S)			150	mW
Operating temperature	Topr			-30		+70	°C
Storage temperature	Tstg			-55		+125	°C

Absolute Maximum Ratings at $Ta=25^{\circ}C,\,V_{SS}$ = 0 V

Notes: 1. Values up to the generated oscillator amplitude are allowed when driven internally using the guaranteed circuit constant values with the oscillator circuit shown in figure 2.

2. The average over a 100 ms period.

Allowable Operating Conditions at Ta = -30 to $+70^{\circ}$ C, $V_{SS} = 0$ V, $V_{DD} = 3.0$ to 6.0 V

			Applicable				Ratings		L Locit
	Parameter	Symbol	pins/notes	Conditions	V _{DD} [V]	min	typ	max	Unit
Ope	rating supply voltage	V _{DD}	V _{DD}			3.0		6.0	V
Star	ndby supply voltage	V _{ST}	V _{DD}	RAM and register retention *		1.8		6.0	V
High-level input voltage		V _{IH} 1	PA, PC, PD	Output n-channel transistor off		0.7 V _{DD}		13.5	V
		V _{IH} 2	PE	When the port E input option is selected		0.7 V _{DD}		V _{DD}	V
		V _{IH} 3	RES		1.8 to6.0	0.8 V _{DD}		V _{DD}	V
	V _{IH} 4	OSC1	When the RC oscillator and external clock option is selected		0.8 V _{DD}		V _{DD}	V	
		V _{IL} 1	PA, PC, PD	Output n-channel transistor off		V _{SS}		0.3 V _{DD}	V
		V _{IL} 2	PE	When the port E input option is selected		V _{SS}		0.3 V _{DD}	V
Low	-level input voltage	V _{IL} 3	OSC1	When the RC oscillator and external clock option is selected		V _{SS}		0.25 V _{DD}	V
		V _{IL} 4	TEST			V _{SS}		0.3 V _{DD}	V
		V _{IL} 5	RES			V _{SS}		0.25 V _{DD}	V
	rating frequency (cycle time)	fop(t _{CYC})				200 (20)		4330 (0.92)	kHz (µs)
ns ck	Frequency	fext(text)	OSC1	See Figure 1		200 (20)		4330 (0.92)	kHz (µs)
External clock conditions	Pulse width	textH, textL	OSC1	See Figure 1		69			ns
Exte	Rise and fall times	textR, textF	OSC1	See Figure 1				50	ns
		Cext	OSC1, OSC2	See Figure 2	4 to 6		220 ±5%		pF
two-pin RC oscillator	Two-pin RC oscillator	Cext	OSC1, OSC2	See Figure 2			220 ±5%		рF
	Rext	OSC1, OSC2	See Figure 2	4 to 6		6.8 ±1%		kΩ	
aranti		Rext	OSC1, OSC2	See Figure 2			15.0 ±1%		kΩ
Ö	Ceramic oscillator			See Figure 2			See Table 1		

Note *: Applications must maintain the operating supply voltage (V_{DD}) until the IC has entered the standby state when a HALT instruction is executed. Also, applications must assure that chattering (key bounce) noise is not input to the PA3 pin during a HALT instruction execution cycle.

Electrical Characteristics at Ta = –30 to +70 $^{\circ}C,$ V_{SS} = 0 V, V_{DD} = 3.0 to 6.0 V

		Paramotor	Sumbol	Applicable	Conditions			Ratings		Unit
		Parameter	Symbol	pins/notes	Conditions	V _{DD} [V]	min	typ	max	Unit
High-level input current			l _{IH} 1	PA, PC, PD	$\begin{array}{l} Output n-channel transistor off \\ (Includes the n-channel \\ transistor off leakage current) \\ V_{IN} = 13.5 \ V \end{array}$				5.0	μA
			I _{IH} 2	PE	When the port E input option is selected $V_{IN} = V_{DD}$				5.0	μA
			I _{IH} 3	OSC1	When the RC oscillator and external clock option is selected $V_{IN} = V_{DD}$				1.0	μA
			I _{IL} 1	PA, PC, PD	Output n-channel transistor off (Includes the n-channel transistor off leakage current) $V_{IN} = V_{SS}$		-1.0			μA
Lov	v-le	evel input current	I _{IL} 2	PE	When the port E input option is selected $V_{IN} = V_{SS}$		-1.0			μA
			I _{IL} 3	RES	V _{IN} = V _{SS}		-80	-50		μA
			I _{IL} 4	OSC1	When the RC oscillator and external clock option is selected $V_{IN} = V_{SS}$		-1.0			μA
			V _{OL} 1	PA, PC, PD	I _{OL} = 10 mA				1.5	V
Lov	v-le	evel output voltage	V _{OL} 2	PA, PC, PD	I _{OL} = 1.8 mA (When all port I/O levels are Under 1 mA)				0.4	V
			V _{HIS} 1	RES				0.1 V _{DD}		V
Hysteresis voltage		V _{IHS} 2	OSC1*1	When the RC oscillator and external clock option is selected			0.1 V _{DD}		V	
		coscillator	ID _{DOP} 1	V _{DD}	Figure 2. 850 kHz (TYP)			5	8	mA
F	RC		ID _{DOP} 2	V _{DD}	Figure 2. 400 kHz (TYP)			4.5	7	mA
			ID _{DOP} 3	V _{DD}	Figure 3. 4 MHz, 1/1, 1/3, and 1/4 divisor ratios			5	8	mA
	~	eremie eesilleter*?	ID _{DOP} 4	V _{DD}	Figure 3. 2 MHz, 1/1, 1/3, and 1/4 divisor ratios			4.5	7	mA
Current arain	U	Ceramic oscillator*2	ID _{DOP} 5	V _{DD}	Figure 3. 800 kHz, 1/1 divisor ratio			5	8	mA
Currer			ID _{DOP} 6	V _{DD}	Figure 3. 400 kHz, 1/1 divisor ratio			4.5	7	mA
	Ex	ternal clock*2	ID _{DOP} 7	V _{DD}	200 to 4330 kHz, 1/1, 1/3, and 1/4 divisor ratios			5	8	mA
	<u>.</u>		IDDst1	V _{DD}	Output n-channel transistor off Port = V_{DD}	6		0.05	10	μA
	518	andby mode	IDDst2	V _{DD}	Output n-channel transistor off Port = V_{DD}	3		0.025	5	μA
	RC oscillator		(14050	OSC1, OSC2	Figure 2. Cext = 220 pF \pm 5% Rext = 15.0 k $\Omega \pm$ 1%		275	400	711	kHz
Uscillator characteristics	RC os	Oscillator frequency	fMOSC	OSC1, OSC2	Figure 2. Cext = 220 pF \pm 5% Rext = 6.8 k $\Omega \pm$ 1%	4 to 6	579	850	1179	kHz
				OSC1, OSC2	Figure 3. fo = 4 MHz		3840	4000	4160	kHz
ara	tor	Oscillator frequency	fFOSC*3	OSC1, OSC2	Figure 3. fo = 2 MHz		1920	2000	2080	kHz
	cilla	Oscillator nequency		OSC1, OSC2	Figure 3. fo = 800 kHz		768	800	832	kHz
	c os			OSC1, OSC2	Figure 3. fo = 400 kHz		384	400	416	kHz
SS	Ceramic oscillator				Figure 4. fo = 4 MHz				10	ms
Cer	Cer	Oscillator stabilization time	tCFS		Figure 4. fo = 2 MHz fo = 800 kHz fo = 400 kHz				10	ms
Pul	l-up	o resistor reset port	Ru		V _{IN} = V _{SS}	5	70	100	150	kΩ
		al reset characteristics: ime	tRST					See Figure 6.		ms
Pin	са	pacitance	Ср		f = 1 MHz $V_{IN} = V_{SS}$ for all input pins other than the measured pin			10		pF

 Image: Intermediate of the intermediate of

Comparator characteristics (When the comparator input option is selected)

at Ta = -30 to $+70^{\circ}$ C, V_{SS} = 0 V, V_{DD} = 3.0 to 6.0 V

Parameter	Symbol	Applicable	Conditions		Ratings			Unit
Falameter		pins/notes	Conditions	V _{DD} [V]	min	typ	max	Unit
Reference input voltage range	VRF _{IN}	V _{REF} 0, 1			V _{SS} + 0.3		V _{DD} – 1.7	V
Common-mode input voltage range	VCMIN	CMP0 to 3			V _{SS}		V _{DD} – 1.7	V
Offset voltage	V _{OFF}		VCMIN = V_{SS} to V_{DD} – 1.7 V			±50	±300	mV
	TRS1		See Figure 5.	4 to 6		1.0	5.0	μs
Response speed	TRS2		See Figure 5.			1.0	200	μs
	I _{IH} 1	V _{REF} 0, 1					1.0	μA
High-level input current	I _{IH} 2	CMP0 to 3	When the feedback resistor option is not selected				5.0	μA
	I _{IL} 1	V _{REF} 0, 1			-1.0			μA
Low-level input current	I _{IL} 2	CMP0 to 3	When the feedback resistor option is not selected		-1.0			μA
Feedback resistance	RCMFB	CMP0 to 3	When the feedback resistor option is selected			460		kΩ

Table 1 Guaranteed Ceramic Oscillator Circuit Constants

	Standard type						Chip type				
Os	cillator type	Manufacturer	Oscillator element	C1	C2	Rd	Manufacturer	Oscillator element	C1	C2	
External capacitor type	4 MHz	Murata Mfg. Co., Ltd.	CSA4.00MG	33 pF ±10%	33 pF ±10%	—	Murata Mfg. Co., Ltd.	CSAC4.00MGC	33 pF ±10%	33 pF ±10%	
		Kyocera Corporation	KBR-4.0MSA	33 pF ±10%	33 pF ±10%	—	—	—	—	_	
	2 MHz	Murata Mfg. Co., Ltd.	CSA2.00MG	33 pF ±10%	33 pF ±10%	—	Murata Mfg. Co., Ltd.	CSAC2.00MGC	33 pF ±10%	33 pF ±10%	
		Kyocera Corporation	KBR-2.0MS	47 pF ±10%	47 pF ±10%	—	—	—	—	_	
	800 kHz -	Murata Mfg. Co., Ltd.	CSB800J	100 pF ±10%	100 pF ±10%	3.3 KΩ	—	—	—	_	
		Kyocera Corporation	KBR-800F/Y	150 pF ±10%	150 pF ±10%	—	—	—	—	_	
	400 kHz	Murata Mfg. Co., Ltd.	CSB400P	220 pF ±10%	220 pF ±10%	3.3 KΩ	—	—	—	_	
		Kyocera Corporation	KBR-400BK/Y	330 pF ±10%	330 pF ±10%	—	—	—	—	_	
type	4 MHz	Murata Mfg. Co., Ltd.	CST4.00MGW	_	_	_	—	—	_	_	
Internal capacitor type		Kyocera Corporation	KBR-4.0MKS	_	_	—	Kyocera Corporation	KBR-4.0MWS	_	_	
	2 MHz	Murata Mfg. Co., Ltd.	CST2.00MG	_	_	_	_	_	_	_	
		_	_	_	_	_	Kyocera Corporation	KBR-2.0MWS	_	—	



Figure 1 External Clock Input Waveform







Figure 3 Ceramic Oscillator Circuit







Figure 5 Comparator Response Speed TRS Timing



Note: The reset period due to a CRES with a value of 0.68 μF will be 10 to 100 ms when the power supply rise time is zero.

If the power supply rise time is relatively long, increase the value of CRES so that the reset time is at least 10 ms, which is the oscillator stabilization time.

Figure 6 Reset Circuit

Notes on Mounting Preconditions for One-Time Programmable Microcontrollers

This product is provided in both DIP and MFP packages. Since the mounting preconditions are different for these two package types, implement the flowchart appropriate for the product used.



See the following item for details on the screening conditions.

Notes on One-Time Programmable Microcontroller Screening

Due to the structure of their circuits, it is not possible for Sanyo to fully test one-time programmable microcontroller products before the PROM has been written. To increase the reliability after the PROM has been written, we strongly recommend screening these products after writing according to the following flowchart.



Due to the structure of the one-time programmable microcontroller PROM circuit in the state before writing, it is not possible to write test all the bits in the device. This means that it is impossible to guarantee a yield of 100%.

- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
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